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Vishay Semiconductors

ROHS

HALOGEN

FREE

High Voltage, Input Rectifier Diode, 20 A





2L TO-220 FullPAK

PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V_{R}	800 V, 1200 V			
V _F at I _F	1.1 V			
I _{FSM}	300 A			
T _J max.	150 °C			
Package 2L TO-220 FullPAK				
Circuit configuration Single				

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS	SINGLE-PHASE BRIDGE UNITS					
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	18	22	A			

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Sinusoidal waveform	20	Α				
V _{RRM}	Range	800, 1200	V				
I _{FSM}		300	Α				
V _F	10 A, T _J = 25 °C	1.0	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-20ETS08FP-M3	800	800 900					
VS-20ETS12FP-M3	1200	1300	'				

VS-20ETS08FP-M3, VS-20ETS12FP-M3

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ABSOLUTE MAXIMUM RATING	is			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 51$ °C, 180° conduction half sine wave	20	
Maximum peak one cycle	l	10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied	250	A A ² s
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	300	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	
	1-1	10 ms sine pulse, no voltage reapplied	442	A-S
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST (CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	T _{.1} = 150 °C		10.4	mΩ
Threshold voltage	V _{F(TO)}			0.85	V
Maximum reverse leakage current	1	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
Waximum reverse leakage current	I _{RM}	T _J = 150 °C	VR - Hated VRRM	1.0	IIIA

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage tempera	ture range	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.8	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque	minimum			6.0 (5.0)	kgf · cm
Mounting torque max	maximum			12 (10)	(lbf \cdot in)
			Coop at do 21 TO 200 FullPAI/	20ETS08FP	
Marking device			Case style 2L TO-220 FullPAK	20ETS	S12FP

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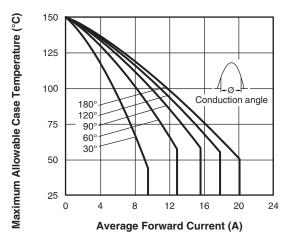


Fig. 1 - Current Rating Characteristics

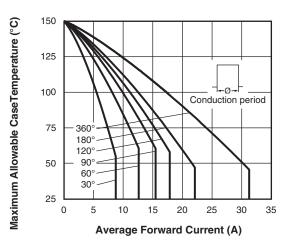


Fig. 2 - Current Rating Characteristics

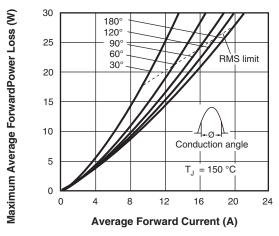


Fig. 3 - Forward Power Loss Characteristics

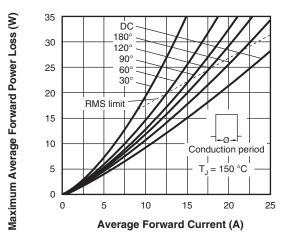


Fig. 4 - Forward Power Loss Characteristics

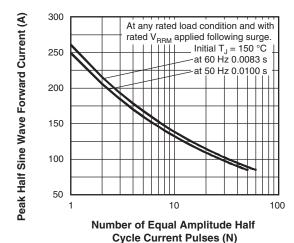


Fig. 5 - Maximum Non-Repetitive Surge Current

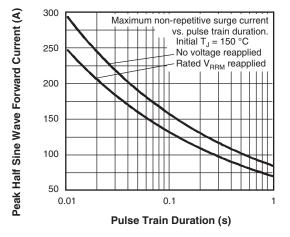


Fig. 6 - Maximum Non-Repetitive Surge Current

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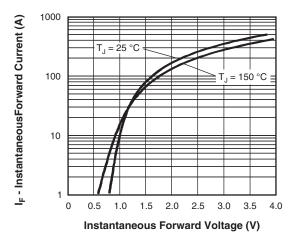


Fig. 7 - Forward Voltage Drop Characteristics

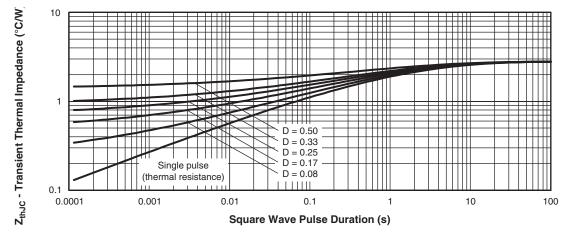


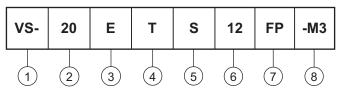
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



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ORDERING INFORMATION TABLE





1 - Vishay Semiconductors product

- Current rating (20 = 20 A)

- Circuit configuration:

E = single diode

- Package:

4 T = TO-220

- Type of silicon:

5 S = standard recovery rectifier

08 = 800 V 12 = 1200 V

____ - Voltage ratings ___ - FullPAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20ETS08FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETS12FP-M3	50	1000	Antistatic plastic tubes		

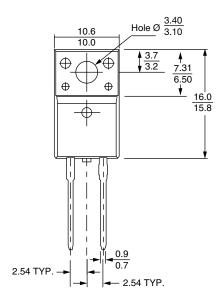
LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?96157</u>			
Part marking information <u>www.vishay.com/doc?95392</u>			

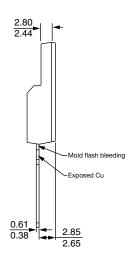


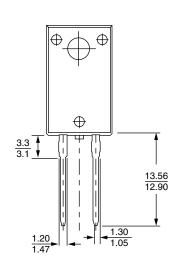
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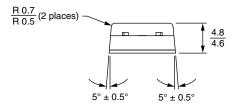
2L TO-220 FullPAK

DIMENSIONS in millimeters









Bottom view



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